

<b>Benchmarks</b>	<b>2006</b>	<b>2012</b>
Feature Size	2 nm	10 nm
No. of devices	4	10e6
Circuit speed	10KHZ	100GHZ
Events/Chip/s	4X10e4	10e14
Power supply	0.1 mV	0.1mV
Power dissipation	1 pW	n/A
Temperature	4K	4K